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Criterion III Metric 3.4.5

NAAC

3rd Cycle

3.4.5 Citation Index

The following are the bibliometric of the publications for the academic year 2016-17 based on average Citation index in Scopus and Web of Science.

S.No	Title of the nener	Name of the	Title of the	Year of the	Citation
-5.110	Title of the paper	Authors	Journal	Publication	Index
1.	Evaluation of an organic	Deepesh V., Verma	Journal of	2016	19
	soil amendment generated	V.K., Suma K., Ajay	Material Cycles		
	from municipal solid waste	S., Gnanavelu A.,	and Waste		
	seeded with activated	Madhusudanan M.	Management		
	sewage sludge				
2.	Protective effect of	Salai Bojan M.,	Nutrition	2016	1
	Raphanus sativus on D-	Rajappa R.,	Clinique et		
	galactosamine induced	Vijayakumar D.R.K.,	Metabolisme		
	nephrotoxicity in rats	Gopalan J.			
3.	Thickness dependence on	Raja S., Bellan C.S.,	Optik	2016	7
	structural, dielectric and	Sundaram S.,			
	AC conduction studies of	Subramani G.,			
	vacuum evaporated Sr	Rajamani R.			
	doped BaTiO3 thin films				
4.	Soret and Dufour effects on	Eswaramoorthi S.,	Scientia Iranica	2016	40
	viscoelastic boundary layer	Bhuvaneswari M.,			
	ow over a stretching surface	Sivasankaran S.,			
	with convective boundary	Rajan S.			
	condition with radiation				
	and chemical reaction				
	1		1		

Table 1: Citation Index for Publication in Scopus





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5.	Antioxidant and free radical	Mohanasundari L.,	International	2016	5
5.	scavenging activity of the	Suja S.	Journal of	2010	U
	scavenging activity of the	suja s.	Journal Of		
	mixture of ethanolic		Pharmacy and		
	extracts of alpinia speciosa		Pharmaceutical		
	and alpinia calcarata		Sciences		
	rhizome				
6.	Pineapple peel waste	Yamuna M.,	International	2016	9
	activated carbon as an	Kamaraj M.	Journal of		
	adsorbent for the effective		ChemTech		
	removal of methylene blue		Research		
	dye from aqueous solution				
7.	Structural and optical	Raja S., Subramani	Optik	2016	14
	properties of vacuum	G., Bheeman D.,			
	evaporated V2O5 thin films	Rajamani R., Bellan			
		С.			

Table 2: Citation Index for Publication in Web of Science

S.No	Title of the paper	Name of the Authors	Title of the Journal	Year of the Publication	Citation Index
1.	Structural and optical	Raja, Sengodan;	OPTIK	2016	13
	properties of vacuum	Subramani, Gopal;			
	evaporated V2O5 thin	Bheeman, Dinesh;			
	films	Rajamani,			
		Ranjithkumar;			
		Bellan,			
		ChandarShekar			





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2.	Thickness dependence on	Raja, Sengodan;	OPTIK	2016	7
	structural, dielectric and	Bellan, Chandar			
	AC conduction studies of	Shekar; Sundaram,			
	vacuum evaporated Sr	Senthilarasu;			
	doped SaTiO(3) thin	Subramani, Gopal;			
	films	Rajamani,			
		Ranjithkumar			
3.	Screening Of	Kavitha, P.;	International	2016	0
	Phytochemical And In-	Sowmia, C.	Journal Of		
	Vitro Antioxidant		Pharmaceutical		
	Property Of A Polyherbal		Sciences And		
	Formulation		Research		
4.	Neighbor Node	Kannan, M.;	2016 ieee	2016	2
	Discovery Mechanism	Jeetha, B. Rosiline	international		
	based Delay Aware		conference on		
	Routing Protocol (DARP		advances in		
	- NND) for Cognitive		computer		
	Radio Ad Hoc Networks		applications		
5.	Soret and Dufour effects	Eswaramoorthi, S.;	Scientia iranica	2016	18
	on viscoelastic boundary	Bhuvaneswari, M.;			
	layer flow over a	Sivasankaran, S.;			
	stretching surface with	Rajan, S.			
	convective boundary				
	condition with radiation				
	and chemical reaction				
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6.	Evaluation of an organic	Deepesh, V.;	Journal of	2016	15
	soil amendment	Verma, Virendra	material cycles		
	generated from	Kumar; Suma, K.;	and waste		
	municipal solid waste	Ajay, Swathi;	management		
	seeded with activated	Gnanavelu, A.;			
	sewage sludge	Madhusudanan, M.			





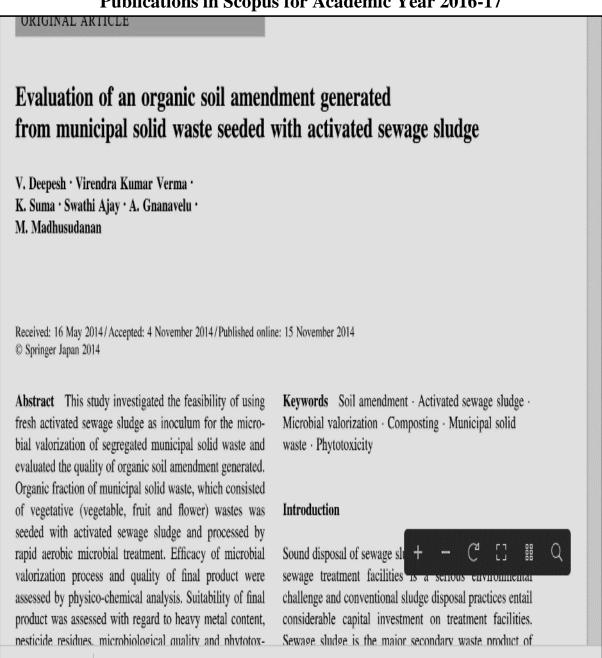
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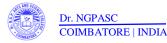
Criterion III Metric 3.4.5

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Publications in Scopus for Academic Year 2016-17







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NAAC 3rd Cvcle

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Criterion III

Metric 3.4.5

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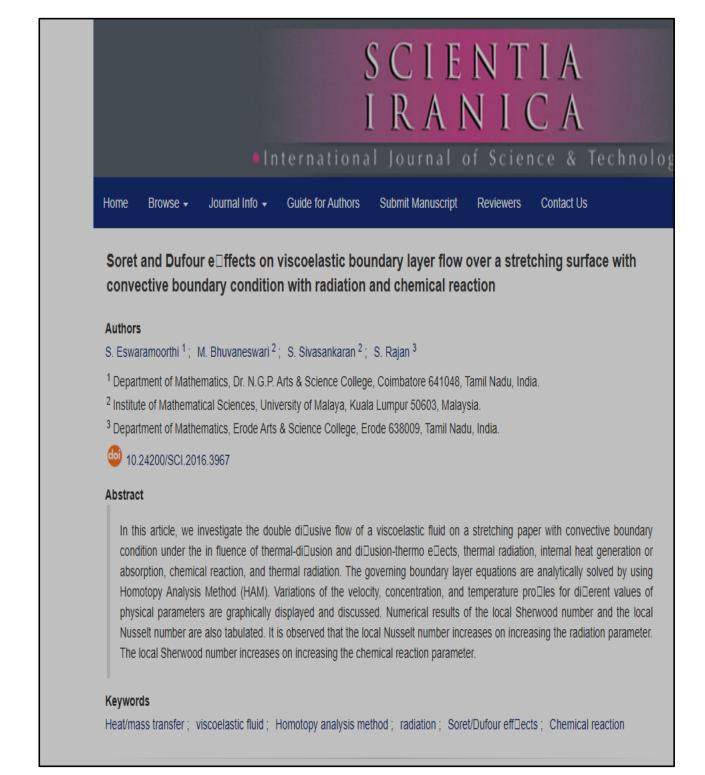
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	ELSEVIER	journal homepage:	journal homepage: www.elsevier.de/ijleo				
1		nce on structural, die evaporated Sr doped I	lectric and AC conduction BaTiO ₃ thin films				
3 Q1 4 5 7 Q2	Ranjithkumar Rajamani ⁴ Department of Physics, Kumaraguru Colle ^b Departments of Physics, Kongunadu Arts ^c Environment and Sustainability Institute,	l ege of Technology, Coimbatore 641049, Tamil N and Science College, G.N-Mills, Coimbatore 641	1029, Tamil Nadu, India				
9 19	ARTICLE INFO ABSTRACT						
11 12 13 14 15	Article history: Received 31 August 2015 Accepted 11 December 2015 Available online xxx	ceived 31 August 2015 method were thermally evaporated on to well cleaned glass substrates under the vacuum of 2 × 10 ⁻⁵ To using 12A4 Hind Hivac coating unit. The thickness of the film was measured by guartz crystal mo					
16 deposited films has a polycrystalline in nature, whereas t 17 Keywords: 18 Barium strontium titanate 19 Thermal evaporation 20 XRD 21 SEM 22 TEM deposited films has a polycrystalline in nature, whereas t 18 temperature. Surface morphology of fabricated thin film 21 SEM 22 TEM			rystalline in nature, whereas the crystallinity of film increases with increase of hology of fabricated thin film observed that very homogeneous and uniform ism in these films under a.c. fields was studied in the frequency range 12 H nperatures (303–483 K). The dependence of dielectric constant and loss fac was investigated and results are discussed. The process of a.c. conduction has s of hopping conduction mechanism. The dielectric constant (ε'), temperatur (TCC) and temperature co-efficient of permitivity (TCP) were estimated. Th				
Q4			energy on thicknesses also studied and reported. © 2015 Published by Elsevier GmbF				
24	1. Introduction	,0	[5] and the solid state reaction of mixed oxide route [6]. Among this method wet chemical method is a promising technique that				
25 26 27 28 29 30 31 32 33	ture is a common ferroelectric constant. It is an attractive mate tilayer capacitor, pyroelectric d memory device, non-volatile m nology, energy storage devices harvesters and positive tempo [PTCR] sensor [1]. Several novel d on Sr doped BaTiO ₃ thin films,	trontium having perovskite struc- material with a high dielectric rial for applications such as mul- etectors, dynamic random access emories, integrated circuit tech- t, field-effect transistors, energy erature coefficient of resistance evices have been fabricated based which include phase shifter, thin vices, ontoelectronic devices and	offers relative low cost, uniform size and homogenous particles A detailed survey of the literature reveals that even though some work on dielectric properties has been carried out to prepare this film of strontium doped barium titanate such as sol-gel method [7,8], r.f. – sputtering [9], pulsed laser ablation [10] and metal organic chemical vapor deposition [11]. No work is found in the literature about to preparation of thin films by vacuum evaporation method using glass substrate. Hence the present paper discusse the structure, dielectric and a.c. conduction mechanism in vacuum evaporated Sr doned BaTilo. thin films				





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Original Article

ANTIOXIDANT AND FREE RADICAL SCAVENGING ACTIVITY OF THE MIXTURE OF ETHANOLIC EXTRACTS OF ALPINIA SPECIOSA AND ALPINIA CALCARATA RHIZOME

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ABSTRACT

Objective: The present study was aimed to investigate the antioxidant and free radipotentials of the mixture ethanolic extract of rhizomes of Alpinia speciosa and Alpinia calcarata.

Methods: The ethanolic mixture extract of rhizomes was prepared in the ratio of 50:50 of *Alpinia speciosa* and *Alpinia calcarata* was subjected to the analysis of phytochemicals, total phenolics and flavonoid contents and free radical scavenging activities such as DPPH, Nitric oxide radical, Superoxide radical, Hydroxyl radical, Ferric reducing antioxidant power, reducing power and Metal ion-chelating activities were determined.

Results: The rhizome mixture extract showed total antioxidant content, good flavonoid and moderate amounts of phenolics content. In DPPH, Nitric oxide and Superoxide radical scavenging activity, IC_{50} was found 136.22±3.44 µg/ml, 53.67±0.47µg/ml, 74.20±1.48µg/ml respectively with the standard ascorbic acid [3.61±0.20 µg/ml, 49.06±0.18 µg/ml and 39.81±0.22 µg/ml]. For the Hydroxyl radical scavenging activities, the IC_{50} values were 42.02±2.51 µg/ml with the standard Rutin [17.15±0.02 µg/ml]. The Ferric reducing antioxidant power was found 497.32±7.49 mmol/Fe [II]g



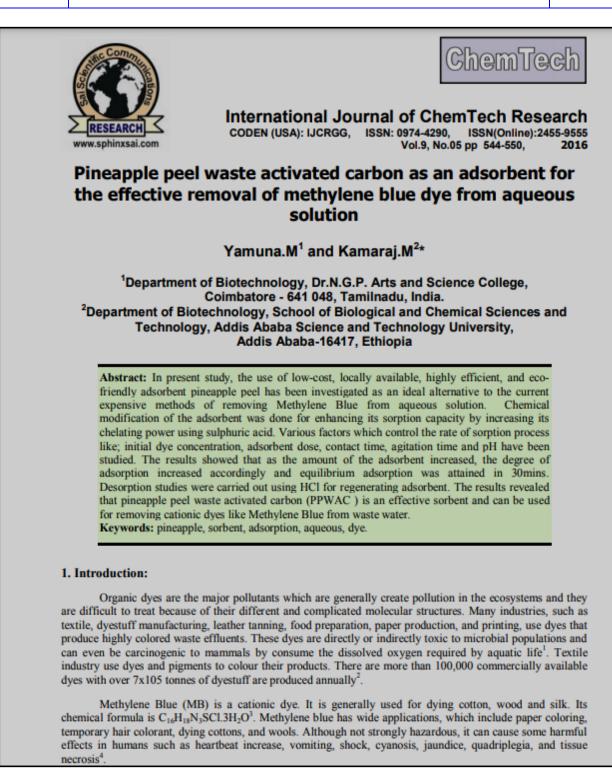


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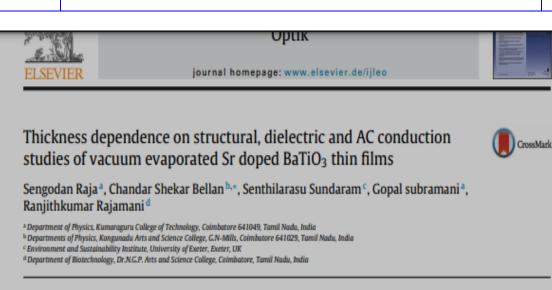
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Sengodan Raja ^a , Gopal sul	oramani ^a , Dinesh Bheema	ın ^b , Ranjithkumar Rajamani ^c ,	
ChandarShekar Bellan ^{d,*}			
* Department of Physics, Kumaraguru College	of Technology, Coimbatore, Tamil Nadu 641	005. India	
Kesearch Division, The NEAK Foundation, Tr	e Nilgiris, Tamil Nadu, India		
⁶ Department of Biotechnology, Dr.N.G.P. Arts			
	and Science College, Coimbatore, Tamil Nad	lu, India	
^c Department of Biotechnology, Dr.N.G.P. Arts ^d Department of Physics, Kongunadu Arts and 	and Science College, Coimbatore, Tamil Nad I Science College, Coimbatore, Tamil Nadu 64	lu, India	
^c Department of Biotechnology, Dr.N.G.P. Arts ^d Department of Physics, Kongunadu Arts and A R T I C L E I N F O Article history: Received 24 July 2014	and Science College, Coimbatore, Tamil Nadu 64 I Science College, Coimbatore, Tamil Nadu 64 A B S T R A C T Thin films of vanadium pen	u, India 11029, India Itoxide (V2O5) have been deposited on to well-clean	
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^c Department of Biotechnology, Dr.N.G.P. Arts ^d Department of Physics, Kongunadu Arts and A R T I C L E I N F O Article history: Received 24 July 2014	and Science College, Colmbatore, Tamil Nadu 64 I Science College, Colmbatore, Tamil Nadu 64 A B S T R A C T Thin films of vanadium pen a vacuum of 10 ⁻⁵ torr usin by the multiple beam inte structural, morphological a	u, India 11029, India Itoxide (V ₂ O ₅) have been deposited on to well-clean 1g 12A4 Hind Hivac coating unit. The thickness of rferometry technique and cross checked by using 1nd optical properties of deposited V ₂ O ₅ films were	the films was measure capacitance method. The determined by XRD, SE
^c Department of Biotechnology, Dr.N.G.P. Arts ^d Department of Physics, Kongunadu Arts and A R T I C L E I N F O Article history: Received 24 July 2014 Accepted 18 August 2015 Keywards: Thin films	and Science College, Colmbatore, Tamil Nad I Science College, Colmbatore, Tamil Nadu 64 A B S T R A C T Thin films of vanadium pen a vacuum of 10 ⁻⁵ torr usin by the multiple beam inte structural, morphological a and UV – vis analysis. XRD p	u, India 11029, India Itoxide (V2O3) have been deposited on to well-clean 1g 12A4 Hind Hivac coating unit. The thickness of rferometry technique and cross checked by using 1nd optical properties of deposited V2O5 films were sattern indicates the amorphous nature of the film. A	the films was measure capacitance method. To determined by XRD, SE bsorption co-efficient (or
^c Department of Biotechnology, Dr.N.G.P. Arts ^d Department of Physics, Kongunadu Arts and A R T I C L E I N F O Article history: Received 24 July 2014 Accepted 18 August 2015 Keywords: Thin films Vacuum	and Science College, Colmbatore, Tamil Nad I Science College, Colmbatore, Tamil Nadu 64 A B S T R A C T Thin films of vanadium per a vacuum of 10 ⁻⁵ torr usir by the multiple beam inte structural, morphological a and UV – vis analysis. XRD p extinction co-efficient (K ₁):	u, India 11029, India Itoxide (V ₂ O ₅) have been deposited on to well-clean 1g 12A4 Hind Hivac coating unit. The thickness of rferometry technique and cross checked by using 1nd optical properties of deposited V ₂ O ₅ films were	the films was measure capacitance method. The determined by XRD, SE bsorption co-efficient (al transmission spectrum
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ABSTRACT

Barium titanate (BaTiO₃) doped with Strontium (BST) nanoparticles prepared by using wet chemical method were thermally evaporated on to well cleaned glass substrates under the vacuum of 2×10^{-3} Torr, using 12A4 Hind Hivac coating unit. The thickness of the film was measured by quartz crystal monitor. From X-ray analysis, it has been found that BaTiO₃ nanoparticles possess tetragonal structure and deposited films has a polycrystalline in nature, whereas the crystallinity of film increases with increase of temperature. Surface morphology of the prepared thin film was found to be uniform. The transport mechanism in these films under a.c. fields was studied in the frequency range 12Hz to 100kHz, at different temperatures (303–483 K). The dependence of dielectric constant and loss factor for different thickness was investigated and results are discussed. The process of a.c. conduction has been explained on the basis of hopping conduction mechanism. The dielectric constant (ϵ'), temperature co-efficient of capacitance (TCC) and temperature co-efficient of permitivity (TCP) were estimated. The dependence of activation energy on thickness also studied and reported.

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1. Introduction

Barium titanate doped with strontium having perovskite structure is a common ferroelectric material with a high dielectric constant. It is an attractive material for applications such as multilayer capacitor, pyroelectric detectors, dynamic random access memory device, non-volatile memories, integrated circuit technology, energy storage devices, field-effect transistors, energy harvesters and positive temperature coefficient of resistance [PTCR] sensor [1]. Several novel devices have been fabricated based on Sr doped BaTiO₃ thin films, which include phase shifter, thin film capacitors, photovoltaic devices, optoelectronic devices and humidity sensors. Due to the desirable properties and applications, over the last few decades, synthesis of BaTiO₃ nanoparticles and thin film has attracted great attention. Most of the experimental work carried out so far relate to preparation of nanoparticles like polymeric precursor method [2] co-precipitation, alkoxide hydrol[5] and the solid state reaction of mixed oxide route [6]. Among this method wet chemical method is a promising technique that offers relative low cost, uniform size and homogenous particles. A detailed survey of the literature reveals that even though some work on dielectric properties has been carried out to prepare thin film of strontium doped barium titanate such as sol-gel method [7,8], r.f. – sputtering [9], pulsed laser ablation [10] and metalorganic chemical vapor deposition [11]. No work is found in the literature about to preparation of thin films by vacuum evaporation method using glass substrate. Hence the present paper discusses the structure, dielectric and a.c. conduction mechanism in vacuum evaporated Sr doped BaTiO₃ thin films.

2. Experimental details

2.1. Synthesis of BaSrTiO₃ nanoparticles





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evidence or assessm synergistic effect as combination of med phenolic and alkaloi polyherbal formulat	plants produce a diverse range of bioactive molecules, making them a rich source of different types of medicines. Thus, a proper scientific nent has become the criteria for acceptance of herbal health claims. As such developing a polyherbal formulation will definitely produce needed comparable to standard drugs that are available in market all over the world. The polyherbal formulation, which has a licinal herbs such as <i>Allium sativum, Trigonella foenum-graecum, Linum usitatissimum</i> was tested for its antioxidant activity, total d contents <i>in-vitro</i> . The purpose of the present study was to investigate the <i>in-vitro</i> antioxidant, total phenolic and alkaloid content of ion and its application for treating life threatening diseases such as cancer, cardiac diseases, diabetes mellitus. In this paper we report the ies in order to orient future investigations towards the finding of new, potent, safe and easily available food antioxidants.



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NND) for cognit	discovery mechanism based delay aware routing protocol (DARP — ive radio ad hoc networks te This
A. Kannan ; B. Rosiline Jee 1 Paper Citation	tha All Authors © 🕻 🔘 🖿 🖡
Abstract	Abstract:
Document Sections	 Cognitive Radio ad hoc network is a sort of wireless network. Cognitive radios have the ability to sense the wireless medium. Routing is the major research area and ensuring quality-of-service (QoS) is a challenging
I. Introduction	problem. This paper proposes a neighbor node discovery mechanism based delay aware routing protocol in order to provide QoS in such patwork. Brimany QoS metrics such as throughout and delay can be put into
II. Related Works	order to provide QoS in such network. Primary QoS metrics such as throughput and delay can be put into consideration for evaluating the performance of the proposed protocol DARP-NND. Simulations are passed out
III. Proposed Work	by means of NS2 and the outcomes confirm that the proposed protocol achieves improvement in provisions of increased throughput and reduced delay.

IV/ Cimulation Cottings and





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SCIENTIA I RANICA

Soret and Dufour effects on viscoelastic boundary layer flow over a stretching surface with convective boundary condition with radiation and chemical reaction

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KEY WORD S

Heat/mass transfer; Viscoe lastic fluid; Homotopy analysis method; Radiation; Soret/Dufour effects; Chemical reaction. Abstract. In this article, we investigate the double diffusive flow of a viscoelastic fluid on a stretching paper with convective boundary condition under the influence of thermal-diffusion and diffusion-thermo effects, thermal radiation, internal heat generation or absorption, chemical reaction, and thermal radiation. The governing boundary layer equations are analytically solved by using Homotopy Analysis Method (HAM). Variations of the velocity, concentration, and temperature profiles for different values of physical parameters are graphically displayed and discussed. Numerical results of the local Sherwood number and the local Nusselt number are also tabulated. It is observed that the local Nusselt number increases on increasing the radiation parameter. The local Sherwood number increases on increasing the chemical reaction parameter.

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1. Introduction

The study of viscoelastic boundary layer flow over a stretching surface has attracted considerable attention in the past few years due to many practical applications in industry and technology, e.g. polymer sheet extrusion from a dye, glass fiber, drawing of plastic films, and paper production. The manufacturing processes at high temperature need cooling and the flow may need viscosity to produce a good effect or to reduce the temperature. Heat and mass transfer of a viscoelastic fluid past a stretching vertical sheet was numerically studied by Hayat et al. [1]. They found that the velocity of the fluid and thickness of its boundary layer increased on increasing the viscoelastic parameter. MHD free Chowdhury and Islam [2]. Hayat et al. [3] analyzed the mass transfer of a viscoelastic fluid. The results of the analytical and numerical solutions were compared and established to be in excellent conformations. The mixed convection of a viscoelastic fluid flow over an isothermal flat spherical tube was numerically investigated by Anwar et al. [4]. It was found that the temperature and thermal boundary layer thickness increased when increasing the value of viscoelastic parameter. The effects of variable viscosity and heat transfer of a viscoelastic fluid in a porous medium were numerically studied by Chin et al. [5]. The heat and mass transfer of a viscoelastic fluid was analyzed by Sanjayanand and Khan [6]. It was found that increase





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ORIGINAL ARTICLE

Evaluation of an organic soil amendment generated from municipal solid waste seeded with activated sewage sludge

V. Deepesh · Virendra Kumar Verma · K. Suma · Swathi Ajay · A. Gnanavelu · M. Madhusudanan

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Abstract This study investigated the feasibility of using fresh activated sewage sludge as inoculum for the microbial valorization of segregated municipal solid waste and evaluated the quality of organic soil amendment generated. Organic fraction of municipal solid waste, which consisted of vegetative (vegetable, fruit and flower) wastes was seeded with activated sewage sludge and processed by rapid aerobic microbial treatment. Efficacy of microbial valorization process and quality of final product were assessed by physico-chemical analysis. Suitability of final product was assessed with regard to heavy metal content, pesticide residues, microbiological quality and phytotoxicity. Quality of the soil amendment generated was compared with the control product generated with a commercial microbial inoculum. Phytotoxicity experiments indicated the stimulatory effect of sewage sludge seeded soil amendment on plant growth but inhibition was observed in closed growth test due to the evolution of gaseous phytotoxic agents. The study suggests that segregated municipal solid waste can be effectively valorized with activated non-dewatered sewage sludge as inoculum and the quality of soil amendment generated was comparable to compost intended for unrestricted applications.

V. Deepesh (🖂) · V. K. Verma · A. Gnanavelu · M. Madhusudanan Keywords Soil amendment · Activated sewage sludge · Microbial valorization · Composting · Municipal solid waste · Phytotoxicity

Introduction

Sound disposal of sewage sludge generated from extensive sewage treatment facilities is a serious environmental challenge and conventional sludge disposal practices entail considerable capital investment on treatment facilities. Sewage sludge is the major secondary waste product of municipal wastewater treatment facilities [1]. It is the semisolid or liquid residue generated during the treatment of domestic wastewater, which must be periodically wasted or removed from the system to ensure optimal performance of biological treatment processes. Due to rapid urbanization, more domestic wastewater treatment plants are pressed to operation, and existing facilities upgraded, generating large quantities of sludge which is a serious environmental menace to be managed. Now, environmentally acceptable and viable management of sewage sludge is a critical issue [2] with regard to enormous sludge generation by extensive wastewater treatment facilities [3-5]. Sewage sludge or sewage biosolids are disposed in many ways including, but not limited to, incineration, land filling [1, 6], land

